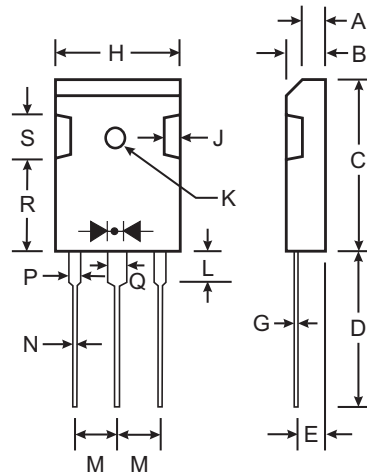


### Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application
- **Lead Free Finish, RoHS Compliant (Note 3)**

### Mechanical Data

- Case: TO-3P
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - Bright Tin. Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Body
- Ordering Information: See Last Page
- Marking: Type Number
- Weight: 5.6 grams (approximate)



| TO-3P                |       |       |
|----------------------|-------|-------|
| Dim                  | Min   | Max   |
| A                    | 1.88  | 2.08  |
| B                    | 4.68  | 5.36  |
| C                    | 20.63 | 22.38 |
| D                    | 18.5  | 21.5  |
| E                    | 2.1   | 2.4   |
| G                    | 0.51  | 0.76  |
| H                    | 15.38 | 16.25 |
| J                    | 1.90  | 2.70  |
| K                    | 2.9Ø  | 3.65Ø |
| L                    | 3.78  | 4.50  |
| M                    | 5.2   | 5.7   |
| N                    | 0.89  | 1.53  |
| P                    | 1.82  | 2.46  |
| Q                    | 2.92  | 3.23  |
| R                    | 11.70 | 12.84 |
| S                    | —     | 6.10  |
| All Dimensions in mm |       |       |

### Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

| Characteristic                                                                                                        | Symbol                          | SBL<br>1630PT | SBL<br>1635PT | SBL<br>1640PT | SBL<br>1645PT | SBL<br>1650PT | SBL<br>1660PT | Unit          |
|-----------------------------------------------------------------------------------------------------------------------|---------------------------------|---------------|---------------|---------------|---------------|---------------|---------------|---------------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                                | $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | 30            | 35            | 40            | 45            | 50            | 60            | V             |
| RMS Reverse Voltage                                                                                                   | $V_{R(RMS)}$                    | 21            | 24.5          | 28            | 31.5          | 35            | 42            | V             |
| Average Rectified Output Current<br>(Note 1)<br>@ $T_C = 95^{\circ}C$                                                 | $I_O$                           | 16            |               |               |               |               |               | A             |
| Non-Repetitive Peak Forward Surge Current 8.3ms<br>single half sine-wave superimposed on rated load<br>(JEDEC Method) | $I_{FSM}$                       | 250           |               |               |               |               |               | A             |
| Forward Voltage Drop<br>@ $I_F = 8.0A$ , $T_C = 25^{\circ}C$                                                          | $V_{FM}$                        | 0.55          |               |               |               | 0.70          |               | V             |
| Peak Reverse Current<br>at Rated DC Blocking Voltage<br>@ $T_C = 25^{\circ}C$<br>@ $T_C = 100^{\circ}C$               | $I_{RM}$                        | 0.5<br>50     |               |               |               |               |               | mA            |
| Typical Total Capacitance (Note 2)                                                                                    | $C_T$                           | 700           |               |               |               |               |               | pF            |
| Typical Thermal Resistance Junction to Case (Note 1)                                                                  | $R_{\theta JC}$                 | 3.5           |               |               |               |               |               | $^{\circ}C/W$ |
| Operating and Storage Temperature Range                                                                               | $T_j$ , $T_{STG}$               | -65 to +150   |               |               |               |               |               | $^{\circ}C$   |

- Notes: 1. Thermal resistance junction to case mounted on heatsink.  
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.  
3. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.

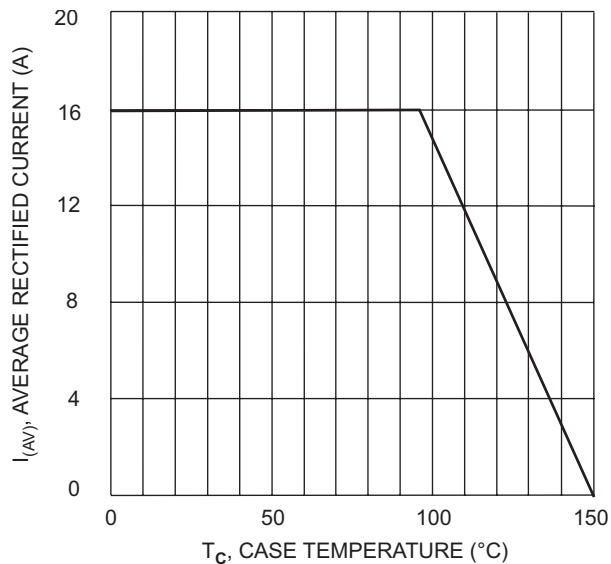


Fig. 1 Forward Current Derating Curve

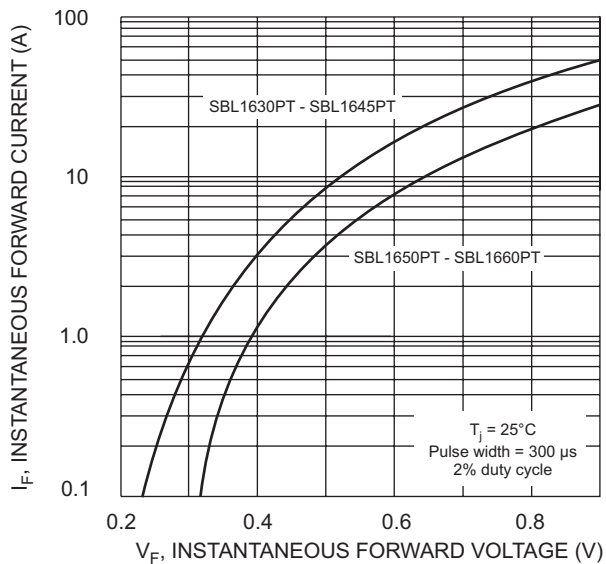


Fig. 1 Typical Forward Characteristics

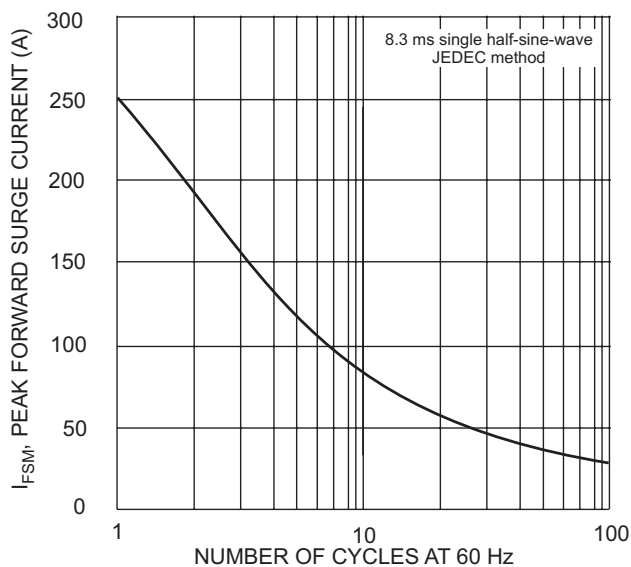


Fig. 3 Max Non-Repetitive Forward Surge Current

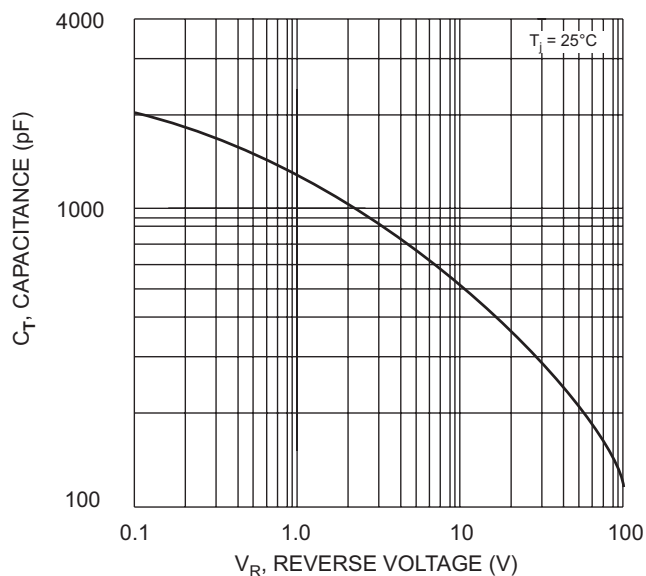


Fig. 4 Typical Total Capacitance per Element

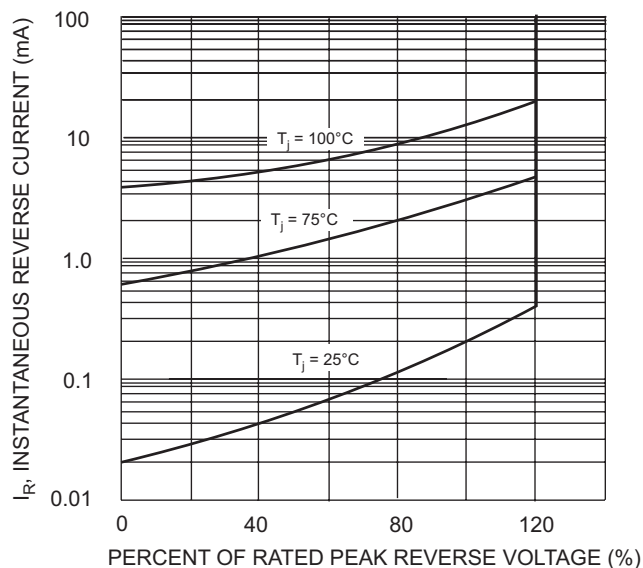


Fig. 5 Typical Reverse Characteristics per Element

**Ordering Information** (Note 4)

| Device    | Packaging | Shipping |
|-----------|-----------|----------|
| SBL1630PT | TO-3P     | 30/Tube  |
| SBL1635PT | TO-3P     | 30/Tube  |
| SBL1640PT | TO-3P     | 30/Tube  |
| SBL1645PT | TO-3P     | 30/Tube  |
| SBL1650PT | TO-3P     | 30/Tube  |

Notes: 4. For packaging details, visit our website at <http://www.diodes.com/datasheets/ap02008.pdf>.